multicomp PRO

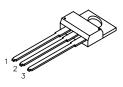


Description:

Plastic NPN TO-220 silicon power transistor is designed for various specific and general purpose applications such as output and driver stages of amplifiers operating at frequencies from DC to greater than 1MHz series shunt and switching regulators low and high frequency inverters/converters and many others.

RoHS Compliant

NPN



Pin Configuration:

1. Base 2. Collector

3. Emitter

Features:

- Very low collector saturation voltage
- Excellent linearity •
- Fast switching

Parameter Symbol Rating Unit Collector-Emitter Voltage 80 V_{CEO} Collector-Base Voltage 80 V V_{CES} 5 Emitter-Base Voltage V_{EBO} Continuous Collector Current I_{C} 10 А 2 **Base Current** А I_{B} Total Device Dissipation at $T_c = 25^{\circ}C$ 50 W P_D Derate above 25°C 0.4 W/°C Operating and Storage -65 to +150 °C T_i, T_{stg} Junction Temperature Range

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Min.	Max.	Unit		
OFF Characteristics	· · ·		р. 				
Collector - Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =30mA, I _B =0	80	-	V		
Collector Cut-Off Current	I _{CES}	V _{CE} =80V, V _{BE} =0	-	10	μA		
Emitter Cut-Off Current	I _{EBO}	V_{EB} =5V, I_{C} =0	-	100			
ON Characteristics							
DC Current Gain	h	V _{CE} =1V, I _C =2A	35	-	-		
	h _{FE} -	V _{CE} =1V, I _C =4A	20	-	-		
Collector - Emitter Saturation Voltage	V _{CE(sat)}	I _C =8A, I _B =800mA	-	1	V		
Base - Emitter Saturation Voltage	V _{BE(sat)}	I _C =8A, I _B =800mA		1.5	V		

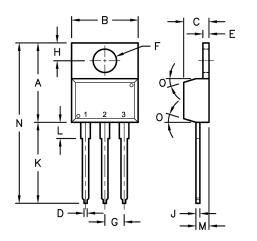
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Bipolar Transistor

Electrical Characteristics (T_a = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Max.	Unit
Small-Signal Characteristics					
Current Gain-Bandwidth Product	f _T	V _{CE} =10V, I _C =500mA, f=0.5MHz	15	-	MHz
Output Capacitance	C _{obo}	V _{CB} =10V, I _E =0, f=1MHz	220	-	pF
Switching Characteristics					
Rise Time	t _r		-	0.5	
Storage Time	t _s	I _C =5A, I _{B1} =I _{B2} =500mA	-	1	μA
Fall Time	t _f		-	0.4	



Pin Configuration:

- 1. Base
- 2. Collector
- 3. Emitter

Dimensions	А	В	С	D	E	F	G	Н	J	K	L	М	N	0
Min.	14.42	9.63	3.65	-	1.15	3.75	2.29	2.54	-	12.7	2.8	2.03	-	7 °
Max.	16.51	10.67	4.83	0.9	1.4	3.88	2.79	3.43	0.56	14.73	4.07	2.92	31.24	7°

Dimensions : Millimetres

Part Number Table

Description	Part Number				
Transistor, NPN, 10A, 80V, TO-220	D44H10				

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